

NextPower 80 V, 1.8 mOhm, 270 Amp, N-channel MOSFET in LFPAK88 package **16 December 2022**

Product data sheet

1. General description

NextPower 80 V, standard level gate drive MOSFET. Qualified to 175 °C and recommended for industrial and consumer applications.

2. Features and benefits

- Low Q_{rr} for higher efficiency and lower spiking •
- 270 Amps I_{D(max)} continuous current rating
- Low Q_G × R_{DSon} FOM for high efficiency switching applications
- Strong avalanche energy rating (E_{as})
- Avalanche rated and 100% tested
- Ha-free and RoHS compliant LFPAK88 package

3. Applications

- Synchronous rectifier in AC-DC and DC-DC
- Primary side switch in DC-DC •
- BLDC motor control
- Full-bridge and half-bridge applications
- Battery protection

4. Quick reference data

	ck reference data	A 11/1			-		
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	80	V
ID	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>		-	-	270	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	-	341	W
Tj	junction temperature			-55	-	175	°C
Static chara	acteristics	·					
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 11		-	1.35	1.8	mΩ
		V _{GS} = 7 V; I _D = 25 A; T _j = 25 °C; <u>Fig. 11</u>		-	1.7	2.5	mΩ
Dynamic ch	naracteristics						
Q _{GD}	gate-drain charge	$I_D = 25 \text{ A}; V_{DS} = 40 \text{ V}; V_{GS} = 10 \text{ V};$		7	25	58	nC
Q _{G(tot)}	total gate charge	T _j = 25 °C; <u>Fig. 13; Fig. 14</u>		74	148	222	nC
Avalanche	ruggedness		·	·	·		
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	I_D = 89.3 A; V _{sup} ≤ 80 V; R _{GS} = 50 Ω; V _{GS} = 10 V; T _{j(init)} = 25 °C; unclamped; t _p = 182 μs; Fig. 4	[1]	-	-	847	mJ

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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Source-drain d	iode					
Qr		$\begin{split} I_S &= 25 \text{ A}; \text{ d}I_S/\text{d}t = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V}; \\ \text{V}_{DS} &= 40 \text{ V}; \text{ T}_j = 25 ^\circ\text{C}; \text{ Fig. 17} \end{split}$	-	59	-	nC

[1] Protected by 100% test

5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		
2	S	Source		D
3	S	Source	0	
4	S	Source		G(」译本)
mb	D	mounting base; connected to drain	LFPAK88 (SOT1235)	mbb076 S

6. Ordering information

Table 3. Ordering information Type number	Package				
	Name	Description	Version		
PSMN1R8-80SSF	LFPAK88	plastic, single-ended surface-mounted package (LFPAK88); 4 leads; 2 mm pitch; 8 mm x 8 mm x 1.6 mm body	SOT1235		

7. Marking

Table 4. Marking codes				
Type number	Marking code			
PSMN1R8-80SSF	X1F8S80S			

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C	-	80	V
V _{DGR}	drain-gate voltage	25 °C ≤ $T_j ≤ 175$ °C; $R_{GS} = 20 \text{ k}\Omega$	-	80	V
V _{GS}	gate-source voltage		-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>	-	341	W
ID	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	-	270	А
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u>	-	205	А
I _{DM}	peak drain current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$; Fig. 3	-	1158	А
T _{stg}	storage temperature		-55	175	°C

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Symbol	Parameter	Conditions		Min	Max	Unit
Tj	junction temperature			-55	175	°C
T _{sld(M)}	peak soldering temperature			-	260	°C
Source-drain	n diode					
I _S	source current	T _{mb} = 25 °C		-	270	А
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$		-	1158	А
Avalanche r	uggedness				·	
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	$ \begin{split} &I_{D} = 89.3 \text{ A}; \text{V}_{\text{sup}} \leq 80 \text{ V}; \text{R}_{\text{GS}} = 50 \Omega; \\ &\text{V}_{\text{GS}} = 10 \text{ V}; \text{T}_{j(\text{init})} = 25 ^{\circ}\text{C}; \text{ unclamped}; \\ &t_{p} = 182 \mu\text{s}; \underline{\text{Fig. 4}} \end{split} $	[1]	-	847	mJ
I _{AS}	non-repetitive avalanche current	$V_{sup} \le 80 \text{ V}; V_{GS} = 10 \text{ V}; T_{j(init)} = 25 \text{ °C}; R_{GS} = 50 \Omega; Fig. 4$	[1]	-	89.3	A

[1] Protected by 100% test

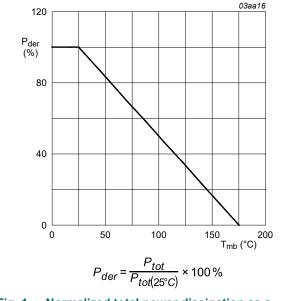
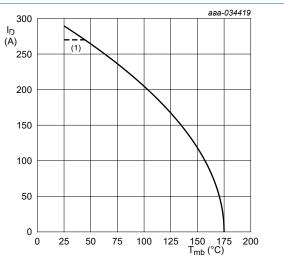


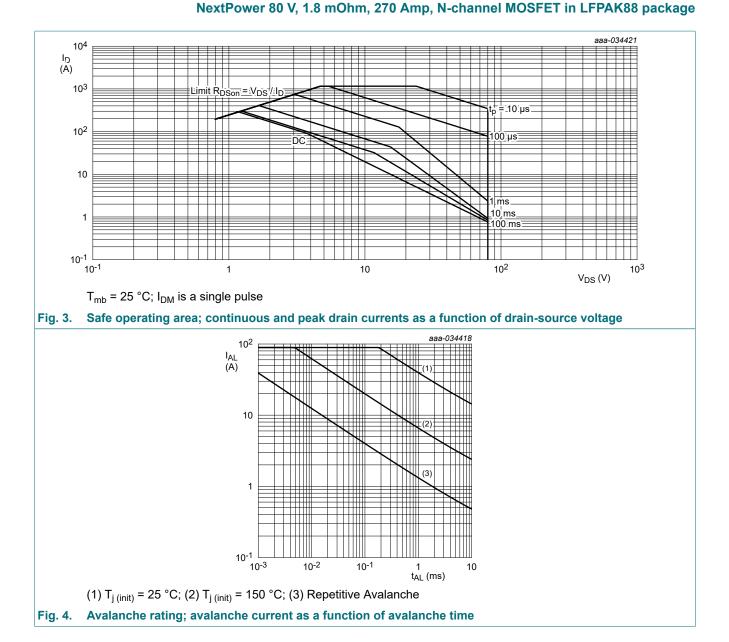
Fig. 1. Normalized total power dissipation as a function of mounting base temperature



 $V_{GS} \ge 10 V$

(1) 270A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

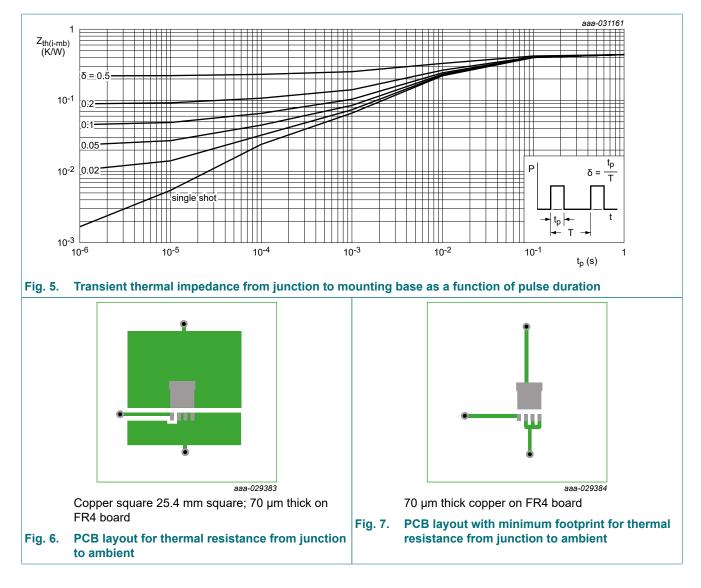
Fig. 2. Continuous drain current as a function of mounting base temperature



9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 5</u>		-	0.2	0.44	K/W
R _{th(j-a)}	thermal resistance from	Fig. 6		-	35	-	K/W
	junction to ambient	Fig. 7		-	70	-	K/W

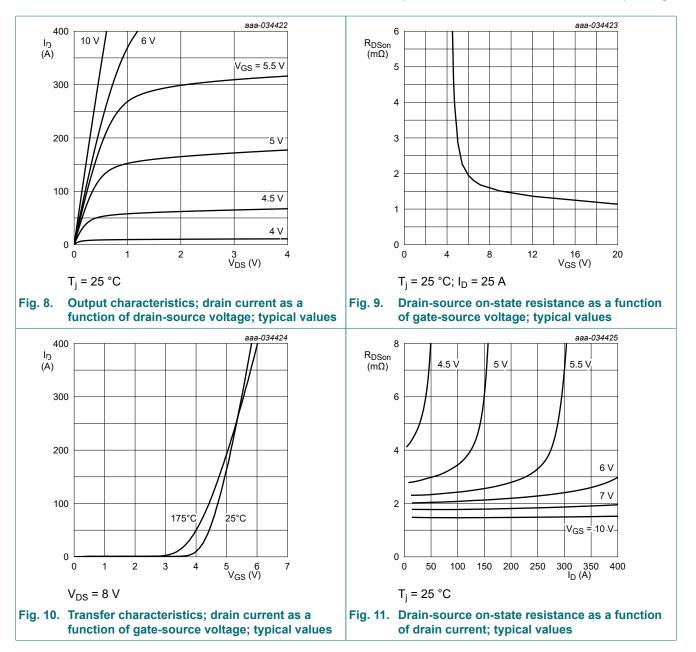


10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static charac	teristics					
V _{(BR)DSS}	drain-source	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	80	-	-	V
	breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = -55 °C	72	-	-	V
V _{GS(th)}	gate-source threshold voltage	I _D = 1 mA; V _{DS} = V _{GS} ; T _j = 25 °C	2	3	4	V
		I _D = 1 mA; V _{DS} = V _{GS} ; T _j = -55 °C	-	3.5	-	V
		I _D = 1 mA; V _{DS} = V _{GS} ; T _j = 175 °C	-	1.6	-	V
$\Delta V_{GS(th)} / \Delta T$	gate-source threshold voltage variation with temperature	25 °C ≤ T _j ≤ 150 °C	-	-8.4	-	mV/K
I _{DSS}	drain leakage current	V _{DS} = 80 V; V _{GS} = 0 V; T _j = 25 °C	-	0.06	1	μA
		V _{DS} = 80 V; V _{GS} = 0 V; T _j = 125 °C	-	20	100	μA
I _{GSS}	gate leakage current	V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	2	100	nA
		V _{GS} = -20 V; V _{DS} = 0 V; T _i = 25 °C	-	2	100	nA

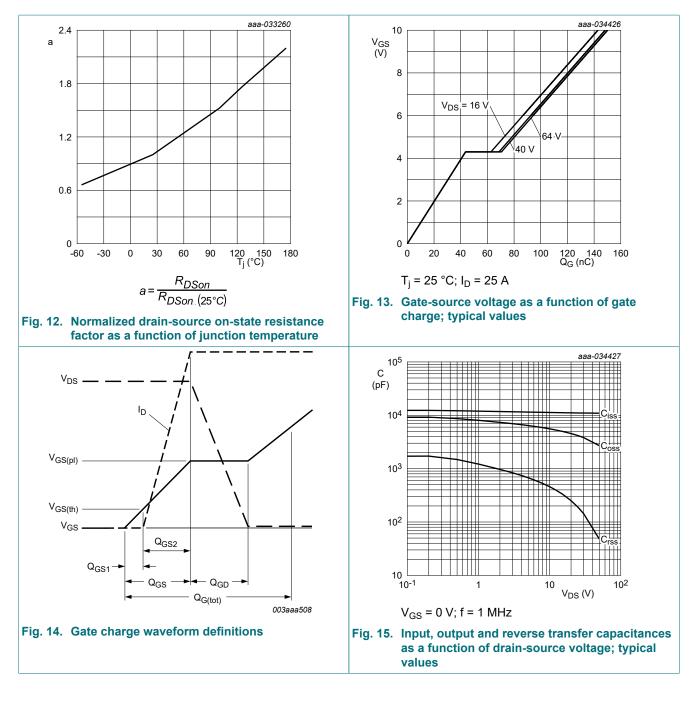
Symbol Conditions Parameter Min Max Unit Тур V_{GS} = 10 V; I_D = 25 A; T_i = 25 °C; drain-source on-state 1.35 1.8 mΩ **R**_{DSon} resistance Fig. 11 V_{GS} = 7 V; I_D = 25 A; T_i = 25 °C; <u>Fig. 11</u> 1.7 2.5 mΩ V_{GS} = 10 V; I_D = 25 A; T_j = 100 °C; 2 2.9 mΩ Fig. 12 V_{GS} = 10 V; I_D = 25 A; T_i = 175 °C; 2.8 4.1 mΩ _ Fig. 12 f = 1 MHz; T_i = 25 °C R_{G} gate resistance 0.8 1.6 3.2 Ω **Dynamic characteristics** total gate charge $I_D = 25 \text{ A}; V_{DS} = 40 \text{ V}; V_{GS} = 10 \text{ V};$ 74 148 222 nC Q_{G(tot)} T_i = 25 °C; <u>Fig. 13; Fig. 14</u> $I_D = 0 A; V_{DS} = 0 V; V_{GS} = 10 V;$ 77 nC T_i = 25 °C I_D = 25 A; V_{DS} = 40 V; V_{GS} = 10 V; Q_{GS} gate-source charge 26 44 62 nC T_i = 25 °C; <u>Fig. 13;</u> <u>Fig. 14</u> nC pre-threshold gate-30 Q_{GS(th)} _ source charge $Q_{GS(\text{th-pl})}$ post-threshold gate-14 nC source charge Q_{GD} gate-drain charge 7 25 58 nC I_D = 25 A; V_{DS} = 40 V; T_i = 25 °C; gate-source plateau 4.3 V V_{GS(pl)} _ voltage Fig. 13; Fig. 14 Ciss input capacitance $V_{DS} = 40 V; V_{GS} = 0 V; f = 0.5 MHz;$ 6565 10946 15319 pF T_i = 25 °C; <u>Fig. 15</u> output capacitance 1925 3209 Coss 5134 pF reverse transfer 8 81 244 pF Crss capacitance $V_{DS} = 40 \text{ V}; \text{ R}_{L} = 1.6 \Omega; \text{ V}_{GS} = 10 \text{ V};$ turn-on delay time 40 ns t_{d(on)} R_{G(ext)} = 5 Ω; T_i = 25 °C rise time 33 tr ns turn-off delay time 90 t_{d(off)} _ ns fall time 45 ns tf Source-drain diode V_{SD} source-drain voltage I_S = 25 A; V_{GS} = 0 V; T_i = 25 °C; <u>Fig. 16</u> 0.8 V 1 $I_{S} = 25 \text{ A}; \text{ d}I_{S}/\text{d}t = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V};$ 56 t_{rr} reverse recovery time ns V_{DS} = 40 V; T_i = 25 °C; <u>Fig. 17</u> Qr recovered charge 59 nC

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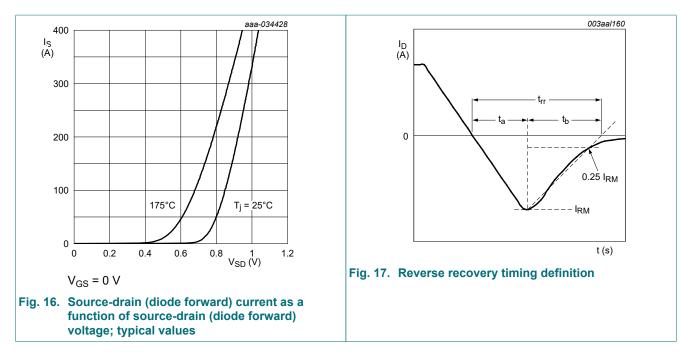


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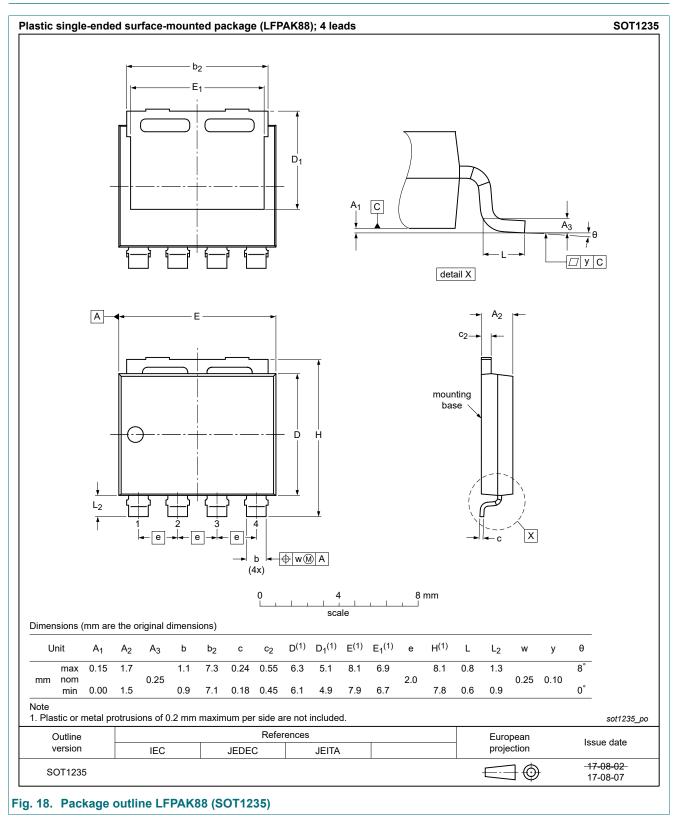


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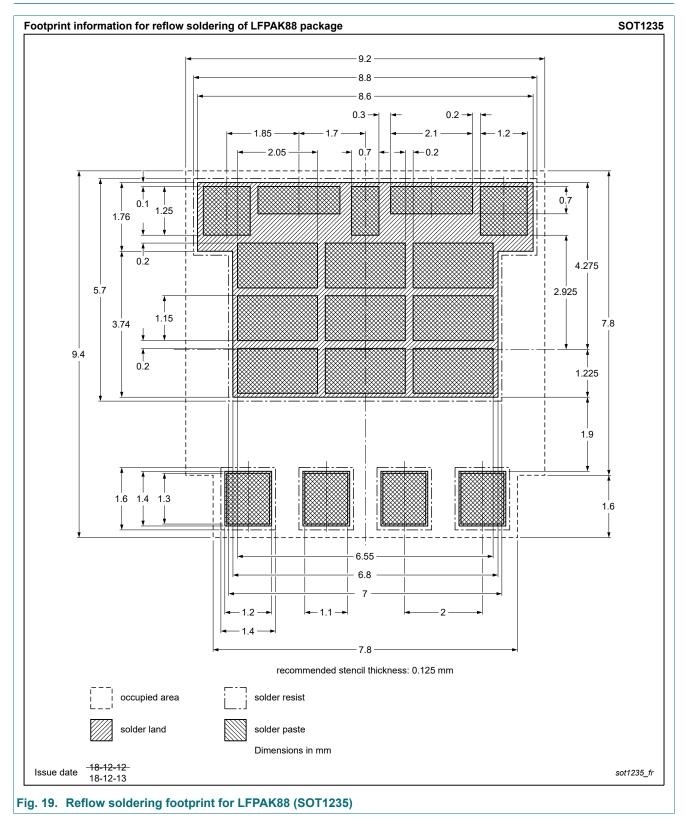


PSMN1R8-80SSF

11. Package outline



12. Soldering



13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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